SP3T DIODE SWITCH

REFLECTIVE AND ABSORPTIVE 0.02-18 GHz

GENERAL INFORMATION

Series VB, VN, switches are medium power devices that operate over commonly used frequency ranges. Carefully selected diodes placed in either series, series-shunt, or shunt configurations produce excellent electrical performance from UHF through KU bands.

GENERAL SPECIFICATIONS

Frequency Coverage:	0.02 to 18.0 GHz.			
RF Impedance:	50 OHMS.			
RF Power:	+20 dBm operational.			
DC Requirements:	Switches require +5 volts at +180 mA			
	and -5 volts at -75 mA supplies.			
	Logic is TTL "0:" when "on" and "1"			
	when "off".			
Temperature Information:	Operating temperature from -55°C to			
	+85°C.			
Switching Speed:	10% to 90% or 90% to 10% of RF.			
	There is an additional 30 nanosec of			
	driver delay.			

| SAR | SAR

SERIES VB, VN

OUTLINE WITH DRIVER

ELECTRICAL PERFORMANCE

Model No.	Туре	Frequency Range GHz	Isolation Minimum dB	Insertion Loss Maximum dB	VSWR Maximum	Speed
VN-11-HASD-1	ABS	0.02-0.07	80	0.65	1.40	500 nsec.
VB-17-SD	REFL	0.1–1.0	80	1.10	1.70	2,000 nsec.
VB-17-HASD	ABS	0.1–1.0	80	1.20	1.70	2,000 nsec.
VB-35-HASD	ABS	0.5–2.0	60	1.10	1.70	2,000 nsec.
VB-37-HASD-1	ABS	0.5–2.0	80	1.30	1.70	100 nsec.
VB-48-HASD	ABS	1.0-6.0	80	1.40	1.70	2,000 nsec.
VB-57-HASD	ABS	2.0-4.0	80	1.30	1.70	2,000 nsec.
VB-73-HASD-2	ABS	2.0-18.0	80	3.60	2.50	20 nsec.
VB-75-HASD	ABS	5.0-10.0	60	1.80	1.70	2,000 nsec.
VB-84-HASD-2	ABS	6.0-18.0	80	3.60	2.50	20 nsec.
VB-95-HASD	ABS	8.0-18.0	80	3.30	2.50	2,000 nsec.
VN-77-ASD	ABS	8.5–9.6	30	1.40	1.50	2,000 nsec.

KEY: Inches[Millimeters] .XX ±.03 .XXX ±.010 [.X ±0.8 .XX ±0.25]



